## **Features**

- · Low-voltage and Standard-voltage Operation
  - -1.8 (V<sub>cc</sub> = 1.8V to 5.5V)
- Internally Organized 512 x 8 (4K), or 1024 x 8 (8K)
- Two-wire Serial Interface
- Schmitt Trigger, Filtered Inputs for Noise Suppression
- Bidirectional Data Transfer Protocol
- 1 MHz (5V), 400 kHz (1.8V, 2.5V, 2.7V) Compatibility
- Write Protect Pin for Hardware Data Protection
- 16-byte Page (4K, 8K) Write Modes
- Partial Page Writes Allowed
- Self-timed Write Cycle (5 ms max)
- High-reliability
  - Endurance: 1 Million Write Cycles
  - Data Retention: 100 Years
- 8-lead PDIP, 8-lead JEDEC SOIC, 8-lead Ultra-Thin Mini-MAP (MLP 2x3), 5-lead SOT23, 8-lead TSSOP and 8-ball dBGA2 Packages
- Lead-free/Halogen-free
- Die Sales: Wafer Form and Tape and Reel

# Description

The AT24C04B/08B provides 4096/8192 bits of serial electrically erasable and programmable read-only memory (EEPROM) organized as 512/1024 words of 8 bits each. The device is optimized for use in many industrial and commercial applications where low-power and low-voltage operation are essential. The AT24C04B/08B is available in space-saving 8-lead PDIP, 8-lead JEDEC SOIC, 8-lead Ultra-Thin Mini-MAP (MLP 2x3), 5-lead SOT23, 8-lead TSSOP, and 8-ball dBGA2 packages and is accessed via a Two-wire serial interface. In addition, the AT24C04B/08B is available in 1.8V (1.8V to 5.5V) version.

SDA [

Figure 1	۱.	Pin Configura	tions
----------	----	---------------	-------

Pin Name	Description			
A0 – A2	Address Inputs			
SDA	Serial Data			
SCL	Serial Clock Input			
WP	Write Protect			
NC	No Connect			
GND	Ground			
V <sub>cc</sub>	Power Supply			

Note: For use of 5-lead SOT23 4K: The software A2 and A1 bits in the device address word must be set to zero to properly communicate. 8K: The software A2 bit in the device address word must be set to zero to properly communicate.

8-lead U	ltra-Thin			
Mini-MAP (	MLP 2x3)	8-	-ball dBG/	42
V <sub>cc</sub> 8	1 A0	$V_{\text{CC}}$	8 1	A0
WP 🔼	🔼 A1	WP	7 2	A1
SCL 6	3 A2	SCL	6 3	A2
SDA 5	GND	SDA	5 4	GND
Bottom	ı View	B	ottom Vie	ew .
8-lead	TSSOP	8	-lead SOI	С
A0 🗆 1	Z 8 □ V <sub>cc</sub>	A0 🕅	1 8	Vcc
A1 🗆 2	7 🗖 WP	A1 🖂	2 7	- WP
A2 🗆 3	6 🗆 SCL	A2 🗔	36	sci
GND 🗖 4	5 🗆 SDA	GND 🖂	4 5	🗆 SD/
5-lead	SOT23	8	-lead PDI	Р
SCL 1	5 🗆 WP	A0 🗆	$1 \bigcirc 8$	
		A1 🗆	2 7	🗆 WP
GND 🔤 2		A2 🗆	36	SCL

 $V_{CC}$ WP SCL

SDA

5 🗆 SDA



**Two-wire** Serial EEPROM 4K (512 x 8) 8K (1024 x 8)

# AT24C04B AT24C08B

Not Recommended for New Design. **Replaced by** AT24C04C or AT24C08C.

5226G-SEEPR-11/09



GND 14

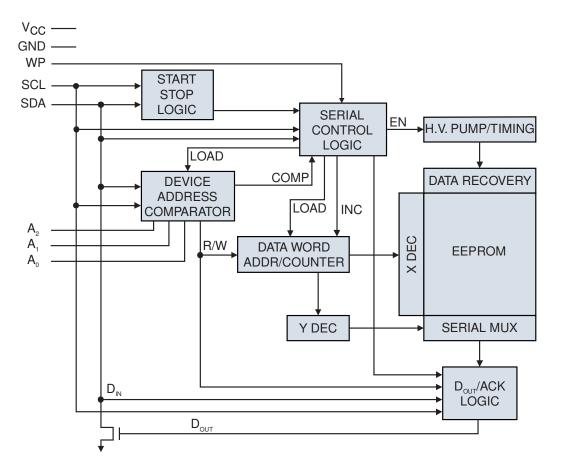


### **Absolute Maximum Ratings**

Operating Temperature55°C to +125°C
Storage Temperature65°C to + 150°C
Voltage on Any Pin with Respect to Ground 0.1V to +7.0V
Maximum Operating Voltage
DC Output Current5.0 mA

\*NOTICE: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### Figure 2. Block Diagram



### 1. Pin Description

SERIAL CLOCK (SCL): The SCL input is used to positive edge clock data into each EEPROM device and negative edge clock data out of each device.

**SERIAL DATA (SDA):** The SDA pin is bidirectional for serial data transfer. This pin is open drain driven and may be wire-ORed with any number of other open-drain or open-collector devices.

**DEVICE/PAGE ADDRESSES (A2, A1, A0):** The AT24C04B uses the A2 and A1 inputs for hard wire addressing and a toal of four 4K devices may be addressed on a single bus system. The A0 pin is a no connect and can be connected to ground (device addressing is discussed in detail under the Device Addressing section).

The AT24C08B only uses the A2 input for hardware addressing and a total of two 8K devices may be addressed on a single bus system. The A0 and A1 pins are no connects and can be connected to ground (device addressing is discussed in detail under the Device Addressing section).

WP Pin Status	Part of the Array Protected			
WF FIII Status	24C04B/08B			
At V <sub>cc</sub>	Full Array			
At GND	Normal Read/Write Operations			





### 2. Memory Organization

**AT24C04B, 4K SERIAL EEPROM:** Internally organized with 32 pages of 16 bytes each, the 4K requires a 9-bit data word address for random word addressing.

AT24C08B, 8K SERIAL EEPROM: Internally organized with 64 pages of 16 bytes each, the 8K requires a 10-bit data word address for random word addressing.

#### Table 2. Pin Capacitance<sup>(1)</sup>

Applicable over recommended operating range from  $T_A = 25^{\circ}C$ , f = 1.0 MHz,  $V_{CC} = +1.8V$ 

Symbol	Test Condition	Max	Units	Conditions
C <sub>I/O</sub>	Input/Output Capacitance (SDA)	8	pF	$V_{I/O} = 0V$
C <sub>IN</sub>	Input Capacitance (A <sub>0</sub> , A <sub>1</sub> , A <sub>2</sub> , SCL)	6	pF	$V_{IN} = 0V$

Note: 1. This parameter is characterized and is not 100% tested.

Applicable over recommended operating range from:

 $T_{AI} = -40^{\circ}C$  to +85°C,  $V_{cc} = +1.8V$  to +5.5V (unless otherwise noted)

Symbol	Parameter	Test Condition	Min	Тур	Max	Units
V <sub>CC1</sub>	Supply Voltage		1.8		5.5	V
V <sub>CC2</sub>	Supply Voltage		2.5		5.5	V
V <sub>CC3</sub>	Supply Voltage		2.7		5.5	V
V <sub>CC4</sub>	Supply Voltage		4.5		5.5	V
I <sub>cc</sub>	Supply Current V <sub>CC</sub> = 5.0V	READ at 100 kHz		0.4	1.0	mA
I <sub>cc</sub>	Supply Current V <sub>CC</sub> = 5.0V	WRITE at 100 kHz		2.0	3.0	mA
I <sub>SB1</sub>	Supply Current V <sub>CC</sub> = 1.8V	$V_{IN} = V_{CC} \text{ or } V_{SS}$		0.6	3.0	μA
I <sub>SB2</sub>	Supply Current $V_{CC} = 2.5V$	$V_{IN} = V_{CC} \text{ or } V_{SS}$		1.4	4.0	μA
I <sub>SB3</sub>	Supply Current $V_{CC} = 2.7V$	$V_{IN} = V_{CC} \text{ or } V_{SS}$		1.6	4.0	μA
I <sub>SB4</sub>	Supply Current V <sub>CC</sub> = 5.0V	$V_{IN} = V_{CC} \text{ or } V_{SS}$		8.0	18.0	μA
I <sub>LI</sub>	Input Leakage Current	$V_{IN} = V_{CC} \text{ or } V_{SS}$		0.10	3.0	μA
I <sub>LO</sub>	Output Leakage Current	$V_{OUT} = V_{CC} \text{ or } V_{SS}$		0.05	3.0	μA
V <sub>IL</sub>	Input Low Level <sup>(1)</sup>		- 0.6		V <sub>CC</sub> x 0.3	V
V <sub>IH</sub>	Input High Level <sup>(1)</sup>		V <sub>cc</sub> x 0.7		V <sub>CC</sub> + 0.5	V
V <sub>OL2</sub>	Output Low Level V <sub>CC</sub> = 3.0V	I <sub>OL</sub> = 2.1 mA			0.4	V
V <sub>OL1</sub>	Output Low Level V <sub>CC</sub> = 1.8V	I <sub>OL</sub> = 0.15 mA			0.2	V

Note: 1.  $V_{IL}$  min and  $V_{IH}$  max are reference only and are not tested.

Table 3. DC Characteristics

#### Table 4. AC Characteristics

Applicable over recommended operating range from  $T_{AI} = -40^{\circ}C$  to  $+85^{\circ}C$ ,  $V_{CC} = +1.8V$  to +5.5V, CL = 1 TTL Gate and 100 pF (unless otherwise noted)

<b>•</b> • • •		1.8, 2	1.8, 2.5, 2.7		5.0-volt	
Symbol	Parameter	Min	Max	Min	Max	Units
f <sub>SCL</sub>	Clock Frequency, SCL		400		1000	kHz
t <sub>LOW</sub>	Clock Pulse Width Low	1.2		0.4		μs
t <sub>HIGH</sub>	Clock Pulse Width High	0.6		0.4		μs
tı	Noise Suppression Time		50		40	ns
t <sub>AA</sub>	Clock Low to Data Out Valid	0.1	0.9	0.05	0.55	μs
t <sub>BUF</sub>	Time the bus must be free before a new transmission can start			0.5		μs
t <sub>HD.STA</sub>	Start Hold Time	0.6		0.25		μs
t <sub>SU.STA</sub>	Start Setup Time	0.6		0.25		μs
t <sub>HD.DAT</sub>	Data in Hold Time	0		0		μs
t <sub>SU.DAT</sub>	Data In Setup Time	100		100		ns
t <sub>R</sub>	Inputs Rise Time <sup>(1)</sup>		0.3		0.3	μs
t <sub>F</sub>	Inputs Fall Time <sup>(1)</sup>		300		100	ns
T <sub>SU.STO</sub>	Stop Setup Time	0.6		.25		μs
t <sub>DH</sub>	Data Out Hold Time	50		50		ns
t <sub>wR</sub>	Write Cycle Time		5		5	ms
Endurancec <sup>(1)</sup>	5.0V, 25°C, Byte Mode	1M		1M		Write cycles

Note: 1. This parameter is ensured by characterization only.





### 3. Device Operation

**CLOCK and DATA TRANSITIONS:** The SDA pin is normally pulled high with an external device. Data on the SDA pin may change only during SCL low time periods (see Figure 6). Data changes during SCL high periods will indicate a start or stop condition as defined below.

**START CONDITION:** A high-to-low transition of SDA with SCL high is a start condition which must precede any other command (see Figure 7).

**STOP CONDITION:** A low-to-high transition of SDA with SCL high is a stop condition. After a read sequence, the stop command will place the EEPROM in a standby power mode (see Figure 7).

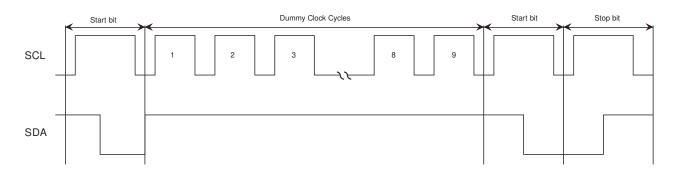
**ACKNOWLEDGE:** All addresses and data words are serially transmitted to and from the EEPROM in 8-bit words. The EEPROM sends a zero to acknowledge that it has received each word. This happens during the ninth clock cycle.

**STANDBY MODE:** The AT24C04B/08B features a low-power standby mode which is enabled:

- (a) Upon power-up and
- (b) After the receipt of the STOP bit and the completion of any internal operations.

**2-WIRE SOFTWARE RESET:** After an interruption in protocol, power loss or system reset, any 2-wire part can be reset by following these steps:

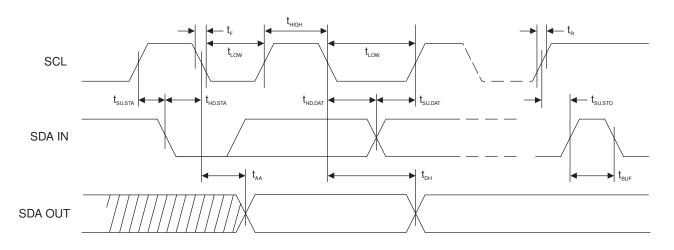
- (a) Create a start bit condition,
- (b) Clock 9 cycles,
- (c) Create another start bit followed by a stop bit condition as shown below. The device is ready for the next communication after the above steps have been completed.





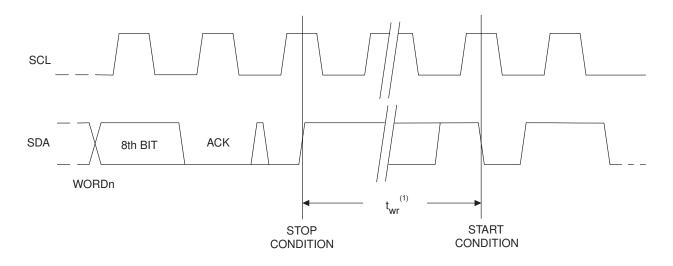
# 4. Bus Timing

Figure 4. SCL: Serial Clock, SDA: Serial Data I/O®



# 5. Write Cycle Timing

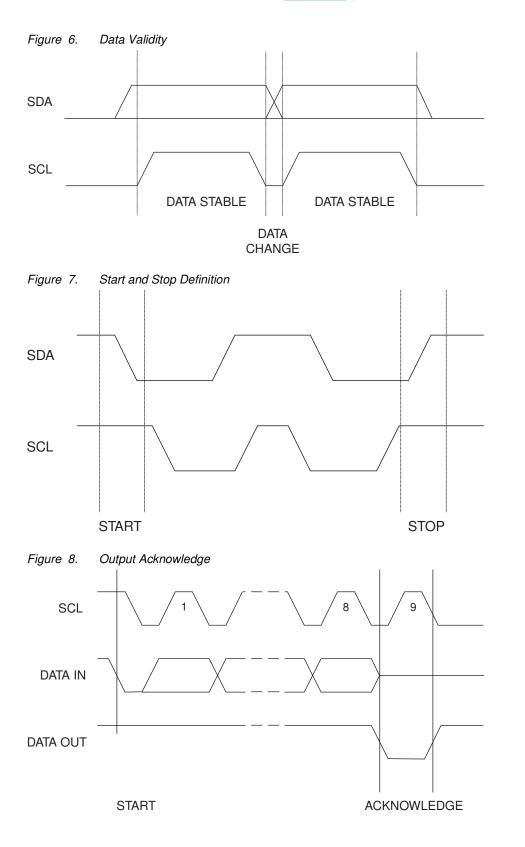
Figure 5. SCL: Serial Clock, SDA: Serial Data I/O



Note: 1. The write cycle time t<sub>WR</sub> is the time from a valid stop condition of a write sequence to the end of the internal clear/write cycle.







8 AT24C04B/08B

### 6. Device Addressing

The 4K and 8K EEPROM device requires an 8-bit device address word following a start condition to enable the chip for a read or write operation (refer to Figure 9).

The device address word consists of a mandatory one, zero sequence for the first four most significant bits as shown. This is common to all the EEPROM devices.

The 4K EEPROM only uses the A2 and A1 device address bits with the third bit being a memory page address bit. The two device address bits must compare to their corresponding hard-wired input pins. The A0 pin is no connect.

The 8K EEPROM only uses the A2 device address bit with the next 2 bits being for memory page addressing. The A2 must compare to its corresponding hard-wired input pin. The A1 and A0 pins are no connect.

For the SOT23 Package Offering:

The 4K EEPROM software A2 and A1 bits in the device address word must be set to zero to properly communicate.

The 8K EEPROM software A2 bit in the device address word must be set to zero to properly communicate.

### 7. Write Operations

**BYTE WRITE:** A write operation requires an 8-bit data word address following the device address word and acknowledgment. Upon receipt of this address, the EEPROM will again respond with a zero and then clock in the first 8-bit data word. Following receipt of the 8-bit data word, the EEPROM will output a zero and the addressing device, such as a microcontroller, must terminate the write sequence with a stop condition. At this time the EEPROM enters an internally timed write cycle,  $t_{WR}$ , to the nonvolatile memory. All inputs are disabled during this write cycle and the EEPROM will not respond until the write is complete (see Figure 10).

**PAGE WRITE:** The 4K/8K EEPROM is capable of an 16-byte page write.

A page write is initiated the same as a byte write, but the microcontroller does not send a stop condition after the first data word is clocked in. Instead, after the EEPROM acknowledges receipt of the first data word, the microcontroller can transmit up to fifteen data words. The EEPROM will respond with a zero after each data word received. The microcontroller must terminate the page write sequence with a stop condition. (see Figure 11).

The data word address lower four bits are internally incremented following the receipt of each data word. The higher data word address bits are not incremented, retaining the memory page row location. When the word address, internally generated, reaches the page boundary, the following byte is placed at the beginning of the same page. If more than sixteen data words are transmitted to the EEPROM, the data word address will "roll over" and previous data will be overwritten.

**ACKNOWLEDGE POLLING:** Once the internally timed write cycle has started and the EEPROM inputs are disabled, acknowledge polling can be initiated. This involves sending a start condition followed by the device address word. The read/write bit is representative of the operation desired. Only if the internal write cycle has completed will the EEPROM respond with a zero allowing the read or write sequence to continue.





#### 8. Read Operations

Read operations are initiated the same way as write operations with the exception that the read/write select bit in the device address word is set to one. There are three read operations: current address read, random address read and sequential read.

**CURRENT ADDRESS READ:** The internal data word address counter maintains the last address accessed during the last read or write operation, incremented by one. This address stays valid between operations as long as the chip power is maintained. The address "roll over" during read is from the last byte of the last memory page to the first byte of the first page. The address "roll over" during write is from the last byte of the current page to the first byte of the same page.

Once the device address with the read/write select bit set to one is clocked in and acknowledged by the EEPROM, the current address data word is serially clocked out. The microcontroller does not respond with an input zero but does generate a following stop condition (see Figure 12).

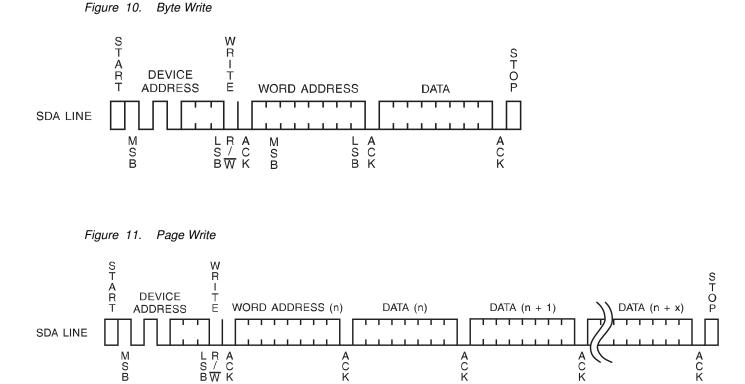
**RANDOM READ:** A random read requires a "dummy" byte write sequence to load in the data word address. Once the device address word and data word address are clocked in and acknowledged by the EEPROM, the microcontroller must generate another start condition. The microcontroller now initiates a current address read by sending a device address with the read/write select bit high. The EEPROM acknowledges the device address and serially clocks out the data word. The microcontroller does not respond with a zero but does generate a following stop condition (see Figure 13).

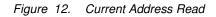
**SEQUENTIAL READ:** Sequential reads are initiated by either a current address read or a random address read. After the microcontroller receives a data word, it responds with an acknowledge. As long as the EEPROM receives an acknowledge, it will continue to increment the data word address and serially clock out sequential data words. When the memory address limit is reached, the data word address will "roll over" and the sequential read will continue. The sequential read operation is terminated when the microcontroller does not respond with a zero but does generate a following stop condition (see Figure 14).

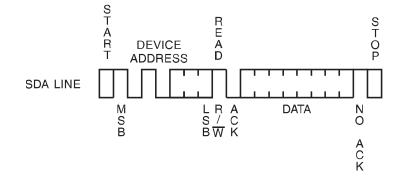
Figure 9.	Device Address
-----------	----------------

4K	1	0	1	0	A <sub>2</sub>	A <sub>1</sub>	P0	R/W
8K	1	0	1	0	A <sub>2</sub>	P <sub>1</sub>	P0	R/W

# Two-wire Serial EEPROM













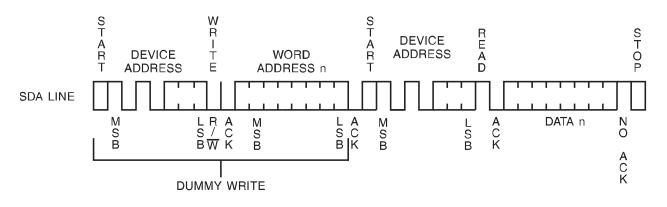
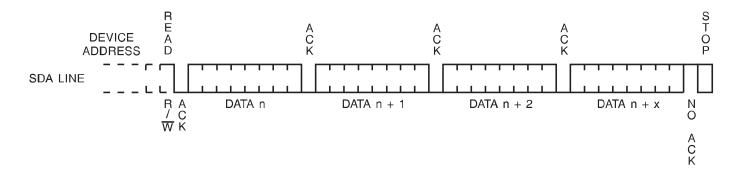


Figure 14. Sequential Read



# 9. AT24C04B Ordering Information

#### Table 5. Ordering Information

Ordering Code	Voltage	Package	Operational range
AT24C04B-PU (Bulk form only)	1.8	8P3	
AT24C04BN-SH-B <sup>(1)</sup> (NiPdAu Lead Finish)	1.8	8S1	
AT24C04BN-SH-T <sup>(2)</sup> (NiPdAu Lead Finish)	1.8	8S1	
AT24C04B-TH-B <sup>(1)</sup> (NiPdAu Lead Finish)	1.8	8A2	Lead-free/Halogen-free/ Industrial Temperature
AT24C04B-TH-T <sup>(2)</sup> (NiPdAu Lead Finish)	1.8	8A2	(–40°C to 85°C)
AT24C04BY6-YH-T <sup>(2)</sup> (NiPdAu Lead Finish)	1.8	8Y6	
AT24C04B-TSU-T <sup>(2)</sup>	1.8	5TS1	
AT24C04BU3-UU-T <sup>(2)</sup>	1.8	8U3-1	
AT24C04B-W-11 <sup>(3)</sup>	1.8	Die Sale	Industrial Temperature (-40°C to 85°C)

Note: 1. "-B" denotes bulk.

"-T" denotes tape and reel. SOIC = 4K per reel. TSSOP, Ultra Thin Mini-MAP, SOT23, and dBGA2 = 5K per reel.

3. Available in tape and reel and wafer form; order as SL788 for inkless wafer form. Please contact Serial Interface Marketing.

I	Package Type						
8P3	8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)						
8S1	8-lead, 0.150" Wide, Plastic Gull Wing Small Outline (JEDEC SOIC)						
8A2	A2 8-lead, 4.4 mm Body, Plastic Thin Shrink Small Outline Package (TSSOP)						
8Y6	8-lead, 2.00 mm x 3.00 mm Body, 0.50 mm Pitch, Ultra Thin Mini-MAP, Dual No Lead Package (DFN), (MLP 2x3 mm)						
5TS1	5-lead, 2.90 mm x 1.60 mm Body, Plastic Thin Shrink Small Outline Package (SOT23)						
8U3-1	J3-1 8-ball, die Ball Grid Array Package (dBGA2)						
Options							
-1.8	Low-voltage (1.8V to 5.5V)						





# 10. AT24C08B Ordering Information

#### Table 6. Ordering Information

Ordering Code	Voltage	Package	Operational range
AT24C08B-PU (Bulk form only)	1.8	8P3	
AT24C08BN-SH-B <sup>(1)</sup> (NiPdAu Lead Finish)	1.8	8S1	
AT24C08BN-SH-T <sup>(2)</sup> (NiPdAu Lead Finish)	1.8	8S1	
AT24C08B-TH-B <sup>(1)</sup> (NiPdAu Lead Finish)	1.8	8A2	Lead-free/Halogen-free/ Industrial Temperature
AT24C08B-TH-T <sup>(2)</sup> (NiPdAu Lead Finish)	1.8	8A2	(-40°C to 85°C)
AT24C08BY6-YH-T <sup>(2)</sup> (NiPdAu Lead Finish)	1.8	8Y6	
AT24C08B-TSU-T <sup>(2)</sup>	1.8	5TS1	
AT24C08BU3-UU-T <sup>(2)</sup>	1.8	8U3-1	
AT24C08B-W-11 <sup>(3)</sup>	1.8	Die Sale	Industrial Temperature (-40°C to 85°C)

Note: 1. "-B" denotes bulk.

2. "-T" denotes tape and reel. SOIC = 4K per reel. TSSOP, Ultra Thin Mini-MAP, SOT23, and dBGA2 = 5K per reel.

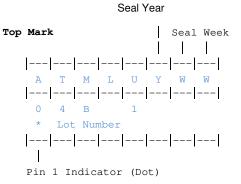
3. Available in tape and reel and wafer form; order as SL788 for inkless wafer form. Please contact Serial Interface Marketing.

	Package Type						
8P3	8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)						
8S1	8-lead, 0.150" Wide, Plastic Gull Wing Small Outline (JEDEC SOIC)						
8A2	8A2 8-lead, 4.4 mm Body, Plastic Thin Shrink Small Outline Package (TSSOP)						
8Y6	Y6 8-lead, 2.00 mm x 3.00 mm Body, 0.50 mm Pitch, Ultra Thin Mini-MAP, Dual No Lead Package (DFN), (MLP 2x3 mm)						
5TS1	5-lead, 2.90 mm x 1.60 mm Body, Plastic Thin Shrink Small Outline Package (SOT23)						
8U3-1	8-ball, die Ball Grid Array Package (dBGA2)						
Options							
-1.8	Low-voltage (1.8V to 5.5V)						

# 11. Part Marketing Scheme

## 11.1. AT24C04B Device Package Marking

### 8-PDIP

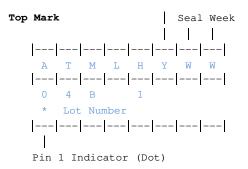


Y = SEAL Y	EAR		WW	=	SEAL	WEEK		
6: 2006	0:	2010	02	=	Week	2		
7: 2007	1:	2011	04	=	Week	4		
8: 2008	2:	2012	::	:	::::	:		
9: 2009	3:	2013	::	:	::::	::		
			50	=	Week	50		
			52	=	Week	52		
Lot Number	Lot Number to Use ALL Characters in Marking							
BOTTOM MARK								

No Bottom Mark

#### 8-SOIC

Seal Year



Y = SEAL YI	EAR		WW =	= SEAL	WEEK
6: 2006	0:	2010	02 =	- Week	2
7: 2007	1:	2011	04 =	- Week	4
8: 2008	2:	2012	:: :	::::	:
9: 2009	3:	2013	:: :	: ::::	::
			50 =	- Week	50
			52 =	- Week	52
Lot Number	to U	se ALL (	Character	s in 1	Marking

Lot Number to Use ALL Characters in Marking BOTTOM MARK

No Bottom Mark

#### 8-TSSOP

Top Mark

.

Pi	n 1	Indi	cato	or	(Dot)
				ı	ī
*		۲ 	-	W	W
0		В		1	-1
					-

Y = SEAL	YEAR		W	v =	SEAL	WEEK
6: 2006	0:	2010	0	2 =	Week	2
7: 2007	1:	2011	0	1 =	Week	4
8: 2008	2:	2012	:	: :	::::	:
9: 2009	3:	2013	:	: :	::::	::
			5	) =	Week	50
			5	2 =	Week	52

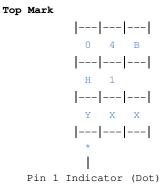
Bottom Mark

Р	Н						
A	A	А	A	А	A	А	А
<-	Pin	1	Indi	cato	r		





#### 8-Ultra Thin Mini Map



#### Y = YEAR OF ASSEMBLY

XX = ATMEL LOT NUMBER TO COORESPOND WITH NSEB TRACE CODE LOG BOOK. (e.g. XX = AA, AB, AC,...AX, AY, AZ)

Y	=	SEAL	YEAR	
6 :	:	2006	0:	2010
7 :	:	2007	1:	2011
8 :	:	2008	2:	2012
9 :	:	2009	3:	2013

#### ULA

Top Mark |---|---| 0 4 B |---|---| Y X X |---|---| \* | Pin 1 Indicator (Dot) Y = BUILD YEAR 2006 = 6 2008 = 8 2007 = 7 Etc. . . XX = ATMEL LOT NUMBER TO COORESPOND WITH NSEB TRACE CODE LOG BOOK. (e.g. XX = AA, AB, AC,...AX, AY, AZ)

### SOT23

Top Mark |---|---|---| 4 B 1 B U |---|---|---|---| Line 1 ----> \* 1

- XX = Device
- V = Voltage Indicator
- W = Write Protect Feature
- U Material Set

Pin 1 Indicator (Dot)

Bottom Mark

Υ = One Digit Year Code Μ = Seal Month (Use Alpha Designator A-L) TC = Trace Code

#### dBGA2

Top Mark

Line 1>	04BU	
Line 2>		
	<	Pin 1 This Corner

- XXX = Device
- U = Material Set
- = One Digit Year Code Υ
- M = Seal Month (Use Alpha Designator A-L) TC = Trace Code





### 11.2. AT24C08B Device Package Marking

#### dBGA2

Top Mark

Line 1 ----> 08BU Line 2 ----> YMXX <----Pin 1 This Corner Y = ONE DIGIT YEAR CODE 8: 2008 1: 2011 9:20092:20120:20103:2013 M = SEAL MONTH (USE ALPHA DESIGNATOR A-L) A = JANUARY B = FEBRUARY . . ...... J = OCTOBER K = NOVEMBER L = DECEMBER

XX = TRACE CODE (ATMEL LOT NUMBERS TO CORRESPOND WITH ATK TRACE CODE LOG BOOK)

#### 8-Ultra Thin Mini MAP

Top Mark

|---|---| 0 8 B |---|---|---| H 1 |---|---|---| Y X X |---|---|---| \* | Pin 1 Indicator (Dot)

Y = YEAR OF ASSEMBLY

 $\label{eq:XX} XX = TRACE ATMEL LOT NUMBER TO COORESPOND WITH TRACE CODE LOG BOOK. (e.g. XX = AA, AB, AC, \dots AX, AY, AZ)$ 

Y = SEAL YEAR

6:	2006	0:	2010
7:	2007	1:	2011
8:	2008	2:	2012
9:	2009	3:	2013

#### 8-PDIP and 8-SOIC



8:	2008	2:	2012	02	=	Week	2
9:	2009	3:	2013	04	=	Week	4
0:	2010	4:	2014	::	:	::::	:
1:	2011	5:	2015	::	:	::::	::
				50	=	Week	50
				52	=	Week	52

#### SOT23

Top Mark

iop naik	
Line 1>	8 B 1 B U
	*
	Pin 1 Indicator (Dot)

BACKSIDE MARKING

|---|---|---| Y M X X |---|---|---|---|

Y = ONE DIGIT YEAR CODE 4: 2004 7: 2007 5: 2005 8: 2008 6: 2006 9: 2009

- J = OCTOBER
- K = NOVEMBER
- L = DECEMBER

XX = TRACE CODE (ATMEL LOT NUMBERS TO CORRESPOND WITH TRACE CODE LOG BOOK)





### 8-TSSOP

Pin 1 Indicator (Dot)
|
|---|---|---|
\* H Y W W
|---|---|---|
0 8 B 1
|---|---|---|

Bottom Mark

-				-				l
	С	0	0					
-				-				l
	A	А	Α	А	А	А	А	
•	<-	Pin	1	Indi	catc	r		

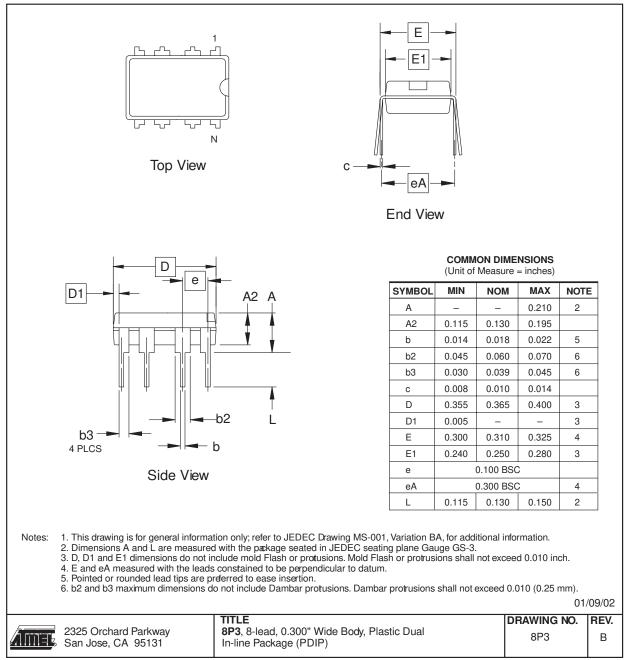
COO = Country of Origin

Y = SEAL YEAR	-	WW = SEAL WEEK
6: 2006	0: 2010	02 = Week 2
7: 2007	1: 2011	04 = Week 4
8: 2008	2: 2012	:: : :::: :
9: 2009	3: 2013	:: : :::: ::
		50 = Week 50
		52 = Week 52

# 12. Packaging Information

## 8P3 – PDIP

Figure 15. 8P3 – PDIP

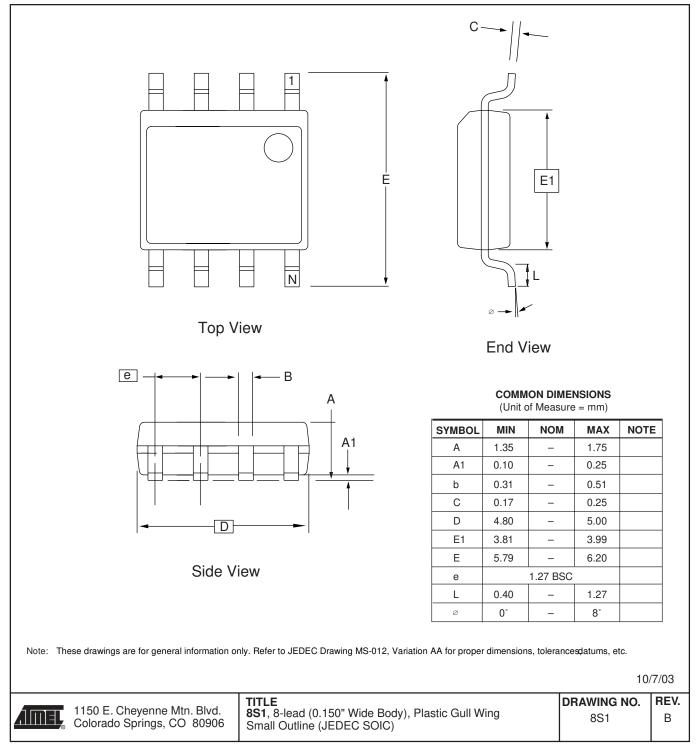






## 8S1 – JEDEC SOIC

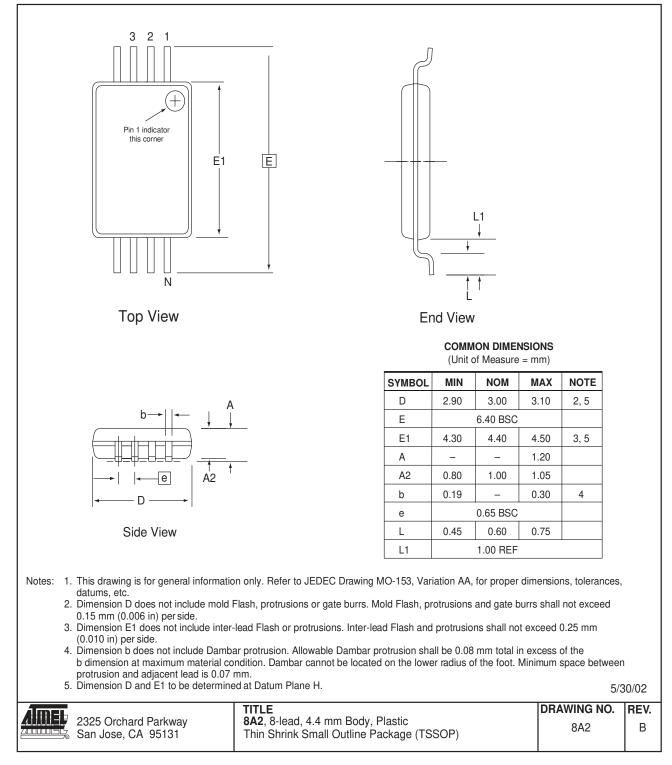
Figure 16. 8S1 – JEDECSOIC



# Two-wire Serial EEPROM

### 8A2 – TSSOP

Figure 17. 8A2 – TSSOP

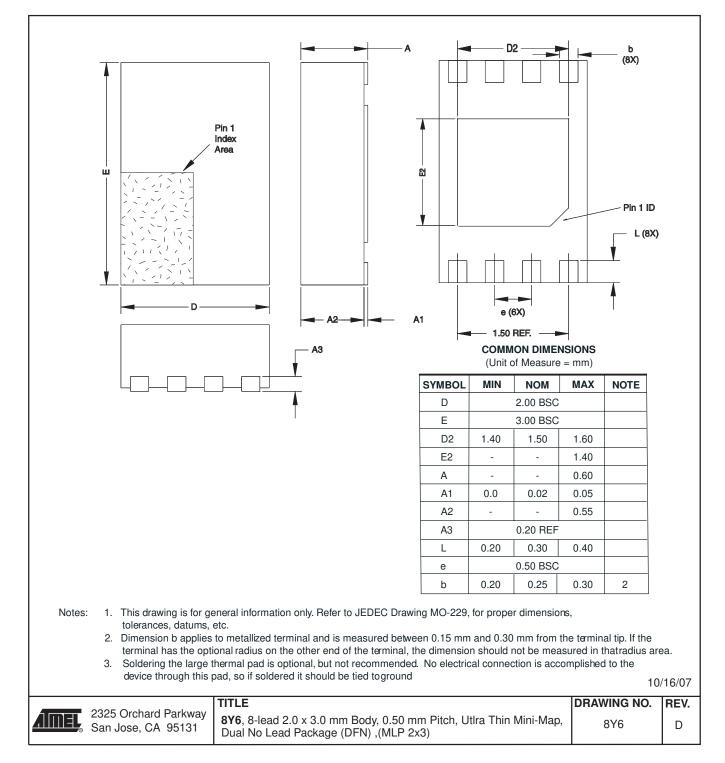






### 8Y6 – Mini Map

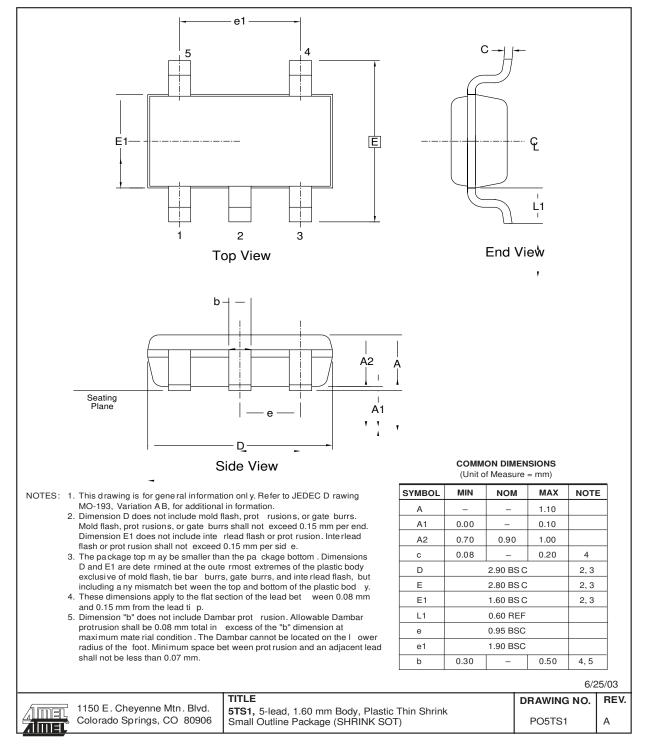
Figure 18. 8Y6 – Mini Map



# Two-wire Serial EEPROM

# 5TS1 – SOT23

Figure 19. 5TS1 – SOT23

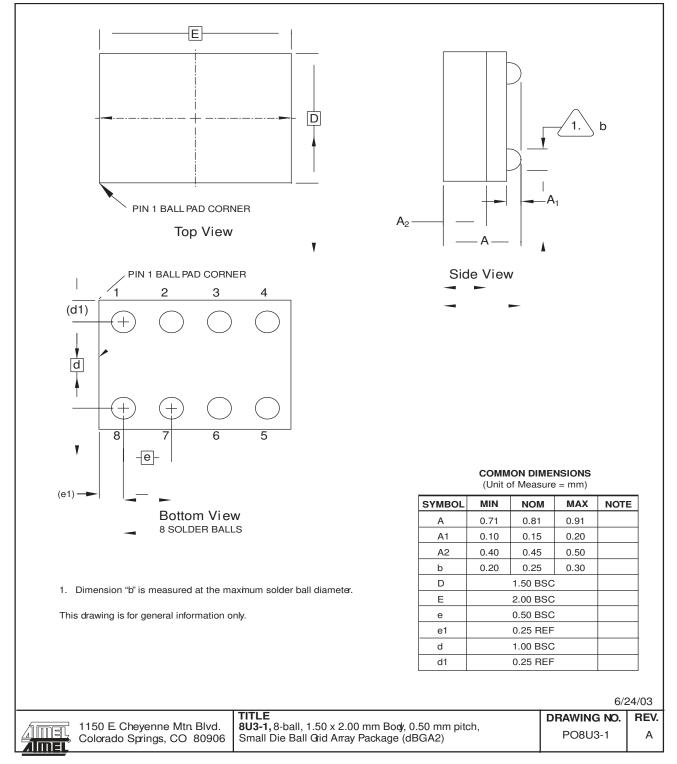






### 8U3-1 - Dbga2

Figure 20. 8U3-1 – Dbga2



# 13. Revision History

#### Table 7. Revision History

Doc. Rev.	Date	Comments
5226G	07/2012	Not recommended for new design. Use AT24C04C/08C.
5226G	11/2009	Corrected AC Characteristics, $T_{AA}$ minimum value from 0.55 to 0.05
5226F	5/2009	Corrected AT24C08B Part Marking Scheme
5226E	12/2008	Add AT24C08B Device Package Marking Details and removed Bumped wafer offering.
5226D	08/2008	Update into MS Format.
5226D	07/2008	Removed 'Preliminary' status
5226C	02/2008	Text changes on page 4 and 9
5226B	08/2007	Updated to new template Updated common Figures Added Package Marking tables
5226A	06/2007	Initial document release





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